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| Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary) | | Application Number | Filed Herewith 10/799 237 | | |
| | | Filing Date | March 11, 2004 | | |
| | | First Named Inventor: | JengPing Lu | | |
| | | Examiner name: unknown E. LESTER | GROUP: unknown 2873 | | |
| Sheet | 1 | of | 1 | Attorney Docket Number | A3490 (XCP-040) |

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| EPH | Fonash: "Integration Of Thin Film Electronics And MEMs", SPIE Vol. 2722(2/96), pp. 66-74. |
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EXAMINER SIGNATURE: *E. Lester*

DATE CONSIDERED: 12-22-04

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